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LV085432905

5/21/03
Mullish

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 10/087,416 ✓
Filing Date February 27, 2002 ✓
Inventor Jigish D. Trivedi et al.
Assignee Micron Technology, Inc.
Group Art Unit 2811
Examiner Douglas W. Owens
Attorney's Docket No. MI22-1965
Title: MOS Transistors With Nitrogen in the Gate Oxide of the P-Channel Transistor



RESPONSE TO JANUARY 17, 2003 OFFICE ACTION

To: Mail Stop Fee Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

From: D. Brent Kenady
Tel. 509-624-4276; Fax 509-838-3424
Wells St. John P.S.
601 West First Avenue, Suite 1300
Spokane, WA 99201-3828

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MAY 20 2003
TECHNOLOGY CENTER 2800

Responsive to the Office Action dated January 17, 2003, Applicant amends
and remarks as follows:

AMENDMENTS

Underlines indicate insertions and ~~strikeouts~~ indicate deletions.